

3.3V CMOS 16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

IDT74LVC162244A

FEATURES:

- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4 w W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- Available in SSOP and TSSOP packages

DRIVE FEATURES:

- · Balanced Output Drivers: ±12mA
- · Low switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

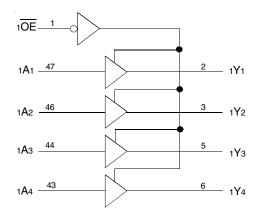
DESCRIPTION:

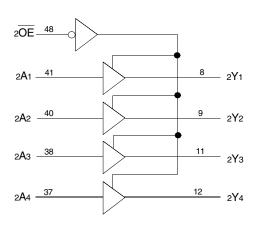
The LVC162244A 16-bit buffer/driver is built using advanced dual metal CMOS technology. The LVC162244A is designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. This device provides true outputs and symmetrical active-low output-enable $\overline{(\overline{OE})}$ inputs.

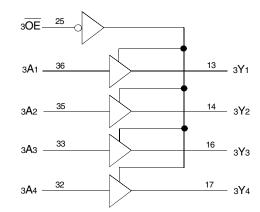
All pins of this 16-bit buffer/driver can be driven from either 3.3V or 5V devices. This feature allows the use of the device as a translator in a mixed 3.3V/5V supply system.

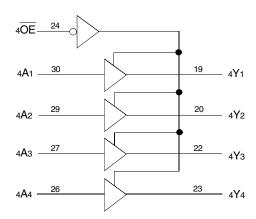
The LVC162244A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been developed to drive ± 12 mA at the designated threshold levels.

FUNCTIONAL BLOCK DIAGRAM







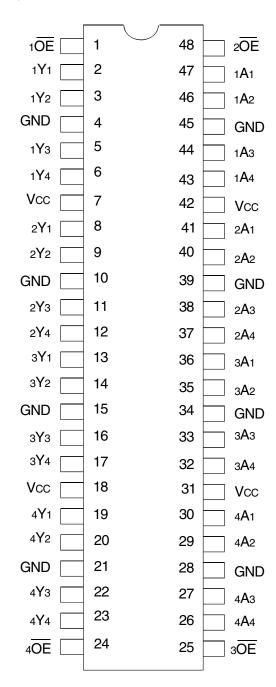


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INDUSTRIAL TEMPERATURE RANGE

JULY 2015

PIN CONFIGURATION



SSOP / TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +6.5	٧
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
lout	DC Output Current	-50 to +50	mA
lık lok	Continuous Clamp Current, VI < 0 or Vo < 0	-50	mA
lcc lss	Continuous Current through each Vcc or GND	±100	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	6.5	8	рF
CI/O	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
xŌĒ	3-State Output Enable Inputs (Active LOW)	
xAx	Data Inputs	
xYx	3-State Outputs	

FUNCTION TABLE (EACH 4-BIT BUFFER)(1)

Inp	Outputs	
х <mark>ОЕ</mark>	xAx	хҮх
L	Н	Н
L	L	L
Н	Х	Z

NOTE:

- 1. H = HIGH Voltage Level
 - X = Don't Care
 - L = LOW Voltage Level
 - Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Co	nditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		T -	_	0.7	V
		Vcc = 2.7V to 3.6V		T -	_	0.8	
Іін	Input Leakage Current	Vcc = 3.6V	Vı = 0 to 5.5V	T -	_	±5	μΑ
lıL							
lozh	High Impedance Output Current	Vcc = 3.6V	Vo = 0 to 5.5V	-	_	±10	μΑ
lozl	(3-State Output pins)						
loff	Input/Output Power Off Leakage	$Vcc = 0V$, $Vin or Vo \le 5.5V$		_	_	±50	μΑ
VIK	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		T -	-0.7	-1.2	V
VH	Input Hysteresis	Vcc = 3.3V		T -	100	_	mV
ICCL	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	T -	_	10	μΑ
ICCH ICCZ			$3.6 \le VIN \le 5.5V^{(2)}$	+		10	
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other inputs at Vcc or GND			_	500	μΑ

NOTES:

- 1. Typical values are at Vcc = 3.3V, +25°C ambient.
- 2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Con	ditions ⁽¹⁾	Min.	Max.	Unit
Voн	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Iон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			Iон = -6mA	1.7	_	
		Vcc = 2.7V	Iон = - 4mA	2.2	_	
			Iон = - 8mA	2	_	
		Vcc = 3V	Iон = -6mA	2.4	_	
			Iон = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IoL = 6mA	_	0.55	
			IOL = 12mA	_	0.8	

NOTE:

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range.

TA = - 40°C to + 85°C.

OPERATING CHARACTERISTICS, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Buffer/Driver Outputs enabled	CL = 0pF, f = 10Mhz	35	pF
CPD	Power Dissipation Capacitance per Buffer/Driver Outputs disabled		4	

SWITCHING CHARACTERISTICS(1)

		Vcc =	: 2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	_	5.6	1.1	4.4	ns
tPHL	xAx to xYx					
tpzh	Output Enable Time	_	6.9	1	5.5	ns
tPZL	xOE to xYx					
tpHz	Output Disable Time	_	6.8	1.8	6.3	ns
tPLZ	xOE to xYx					
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps

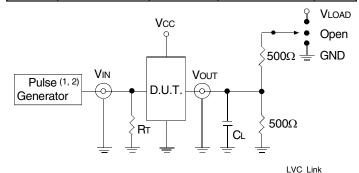
NOTES:

^{1.} See TEST CIRCUITS AND WAVEFORMS. $T_A = -40$ °C to + 85°C.

^{2.} Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	$Vcc^{(1)} = 2.7V$	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	٧
VIH	2.7	2.7	Vcc	٧
VT	1.5	1.5	Vcc/2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

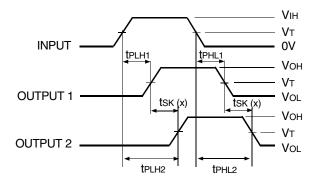
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

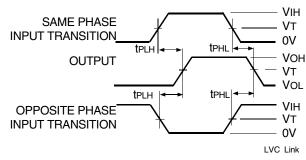


tsk(x) = |tplh2 - tplh1| or |tphl2 - tphl1|

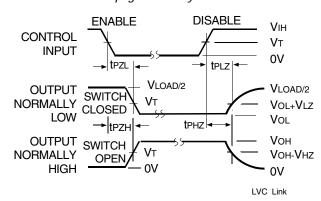
Output Skew - tsk(x)

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



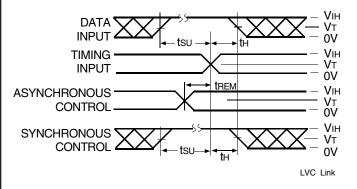
Propagation Delay



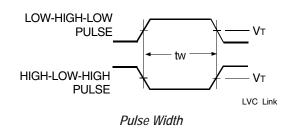
Enable and Disable Times

NOTE:

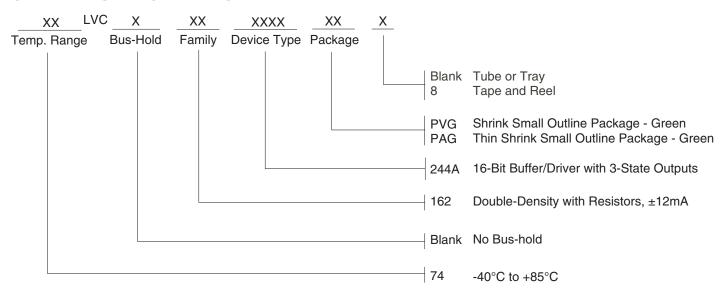
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Set-up, Hold, and Release Times



ORDERING INFORMATION



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(Rev.1.0 Mar 2020)

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